



## Features

- Wide range of operating supply voltage: 2.2V to 5.5V
- Optimized low crystal drive current oscillation for miniature crystal units
- XO5009ALx series: for Wire Bonding
- Recommended oscillation frequency range
- Low frequency Fundamental: 10MHz to 60MHz
- Multi-stage frequency divider for low-frequency output support
- **High Performance(Low Phase Noise/Low Jitter)**
- **High Frequency VS Vdd Stability <+/-1ppm**
- **Ultra-Low Drive Level**
- **Ultra-low Power Current**
- Frequency divider built-in:  
-Selectable by version: f0, f0/2, f0/4, f0/8
- **-55 to 125 °C operating temperature range**
- **50pF output drive capability**
- Standby function
- High impedance in standby mode, oscillator stops
- CMOS output duty level(1/2VDD)  
- $50 \pm 5\%$  output duty
- Die form or Wafer form

## Description

The XO5009ALx series are miniature crystal oscillator module ICs. The oscillator circuit stage has voltage regulator drive, significantly reducing current consumption and crystal current, compared with existing devices, and significantly reducing the oscillator characteristics supply voltage dependency.

## Application

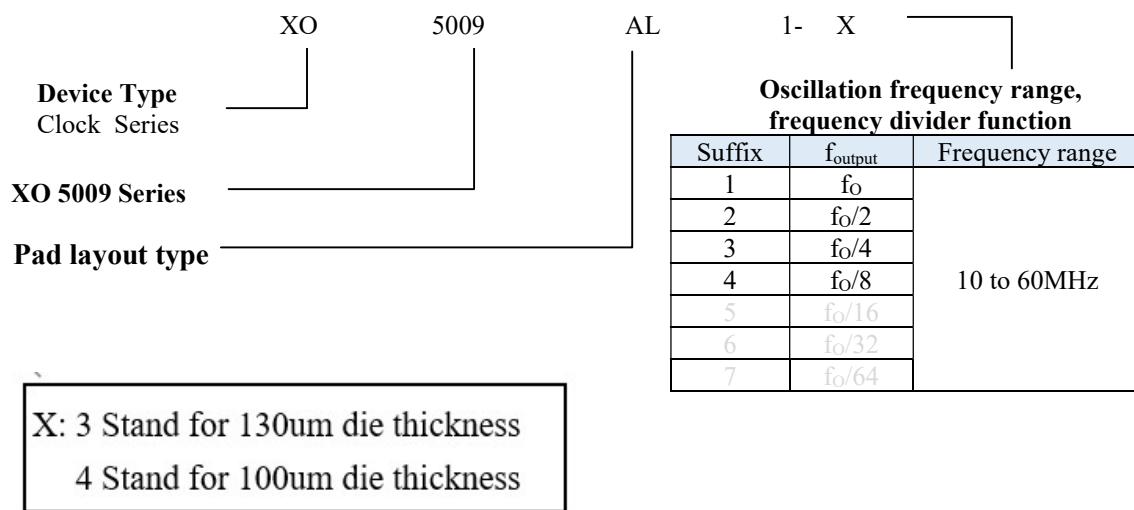
- Used for crystal oscillator
- 7050, 5032 Crystal Oscillator
- 3225, 2520,Crystal Oscillator

## Ordering Information

Part no.	Package type
XO5009ALx-zWF	Wafer form
XO5009ALx-zDE	Die form

Note: 1.Below is the detailed definition of part no.

Note: 2. xx:3/4 , z: -3(130um), -4(100um)

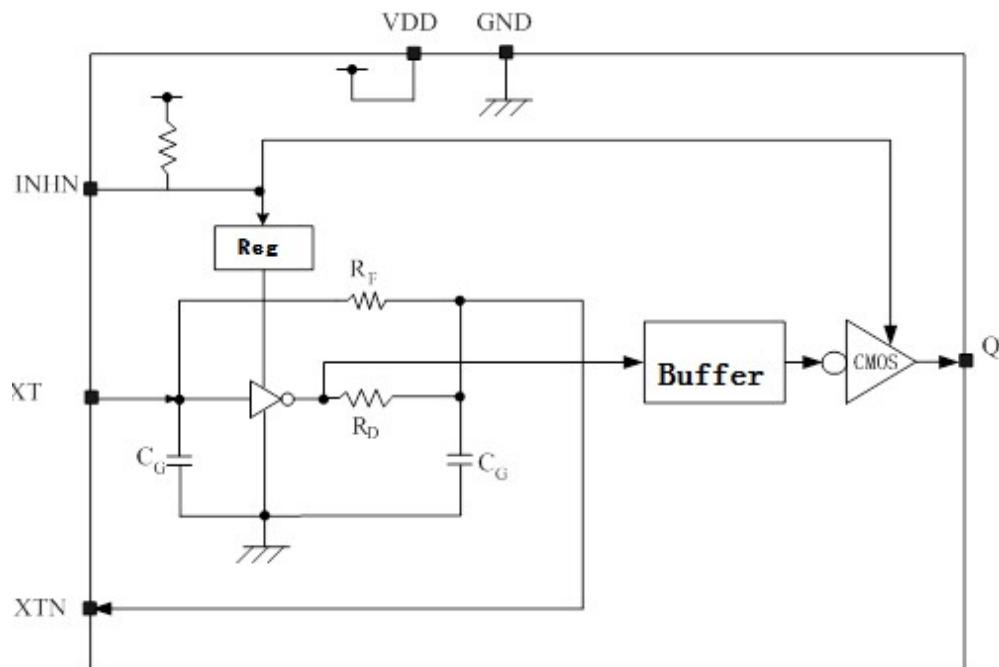




## Series Configuration

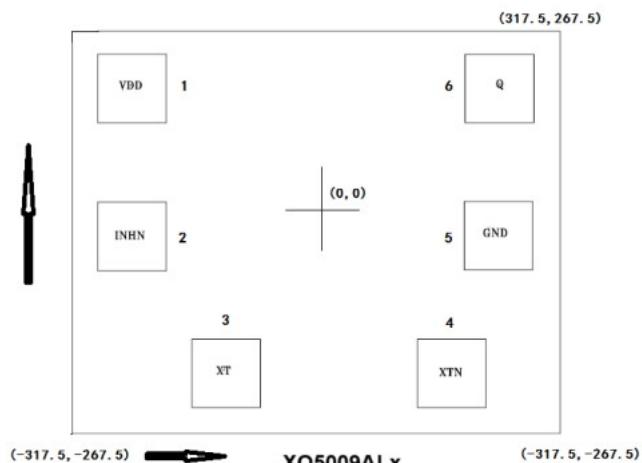
Part No.	Output frequency	Operating supply voltage range(V)	Oscillation mode	Recommended oscillation frequency range*1(MHz)	Output drive capability(mA)	Standby mode	
						Oscillator stop function	Output state
XO5009AL1	f0	2.2~5.5	Fundamental	10 to 60	16	Yes	Hi-Z
XO5009AL2	f0/2						
XO5009AL3	f0/4						
XO5009AL4	f0/8						
XO5009AL5*2	f0/16						
XO5009AL6*2	f0/32						
XO5009AL7*2	f0/64						

## Block Diagram





## Pad Configuration



Pad Coordinate File					
Pad Name	X Coordinate	Y Coordinate	Pad Name	X Coordinate	Y Coordinate
1	-214.85	168	4	158.35	-164.6
2	-214.85	-4.65	5	213.15	-3.85
3	-105.1	-164.6	6	214.2	167.9

**Note:** Substrate is connected to GND or floating.  
**Die Size:** 630μm\*530μm (Including scribe line , Scribe Line Width 60um)  
**Die Thickness:** 130μm±15μm(-3), 100um±15um(-4)  
**Pad Size:** 80μm\*80μm      **Substrate Level:** GND or Floating

## Pad Description

Sym.	Type	Description	
XTN	O	Amplifier output.	Crystal connected between XT and XTN
XT	I	Amplifier input.	
INHN	I	Output state control input. High impedance when LOW. Power-saving pull-up resistor built in.	
V <sub>DD</sub>	P	Supply voltage	
GND	P	Ground	
Q	O	Output. Output frequency determined by internal circuit to one of f <sub>0</sub> ,f <sub>0</sub> /2,f <sub>0</sub> /4,f <sub>0</sub> /8	



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# XO5009ALx-K Series

## High Performance

### Fundamental Crystal Oscillator IC

## Function Description

### Standby Function

When INHN goes LOW, the oscillator stops and the output on Q becomes high impedance.

INHN	Q	Oscillator
HIGH (or open)	$f_0$ output frequency	Normal operation
Low	High impedance	Stopped

### Power-saving Pull-up Resistor

The INHN pin pull-up resistance RUP1 or RUP2 changes in response to the input level(HIGH or LOW). When INHN is tied LOW level, the pull-up resistance is large(RUP1),reducing the current consumed by the resistance. When INHN is left open circuit, the pull-up resistance is small(RUP2),which increases the input susceptibility to external noise. However, the pull-up resistance ties the INHN pin HIGH level to prevent external noise from unexpectedly stopping the output.

### Oscillation Detector Function

The XO5009Lx series also feature an oscillation detector circuit. This circuit functions make the outputs disable until the oscillator circuit starts and oscillation becomes stable. This alleviates the danger of abnormal oscillator output at oscillator start-up when power is applied or when INHN is switched



## Maximum Ratings

Storage Temperature.....	-65°C to +150°C
Supply Voltage to Ground Potential (V <sub>DD</sub> to GND) .....	-0.5V to +7.0V
DC Input (All Other Inputs except V <sub>DD</sub> & GND) ...	-0.5V to V <sub>DD</sub> +0.5V
DC Output.....	-0.5V to V <sub>DD</sub> +0.5V
DC Output Current (all outputs) .....	20mA

**Note:**

Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

## Recommended Operating Conditions

(GND=0V, unless otherwise noted.)

Sym.	Parameter	Series	Conditions	Min	Typ	Max	Unit
V <sub>DD</sub>	Supply voltage	All series	C <sub>L</sub> = 15pF	2.2	-	5.5	V
V <sub>IN</sub>	Input voltage	All series	-	GND	-	VDD	V
T <sub>A</sub>	Operating temperature	All series	-	-55	-	+125	°C
f <sub>0</sub>	Oscillation frequency*1	5009x1-5009x4	V <sub>DD</sub> =2.2V~5.5V -	10	-	60	MHz
f <sub>OUT</sub>	Output frequency	5009x1-5009x4	V <sub>DD</sub> =2.2V~5.5V		-	60	MHz

## Reliability Data

Sym.	Parameter	Series	Conditions	Min	Typ	Max	Unit
ESD	Human Body Model	All series	MIL-STD-883H Method 3015.8	+/-3000	+/-6500		V

Note: Industrial Standard ESD: HBM Model +/-2000V



## DC Electrical Characteristics

XO5009AL1 to XO5009AL6 ( $V_{DD} = 2.5$  to  $5.5V$ ,  $T_A = -40$  to  $85^\circ C$ , unless otherwise noted.)

Sym.	Parameter	Condition	Rating			Unit
			min	typ	max	
$V_{OH}$	HIGH-level output voltage	Q: Measurement cct3, $I_{OH}=8mA$	$V_{DD}-0.4$	-	-	V
$V_{OL}$	LOW-level output voltage	Q: Measurement cct3, $I_{OL}=8mA$	-	-	0.4	V
$V_{IH}$	HIGH-level input voltage	INHN, Measurement cct4	$0.7V_{DD}$	-	-	V
$V_{IL}$	LOW-level input voltage	INHN, Measurement cct4	-	-	$0.3V_{DD}$	V
$I_Z$	Output leakage current	Q: Measurement cct5, INHN=LOW	$V_{OH}=V_{DD}$	-	-	10
			$V_{OL}=GND$	-	-	10
$I_{DD}$	Current consumption	Measurement cct 1, 5009AL1( $f_0$ ),no load INHN=open, $f_0=24MHz$	$V_{DD}=2.5V$	-	0.8	1.6
			$V_{DD}=3.3V$	-	1.1	2.0
			$V_{DD}=5.0V$		1.4	2.8
		Measurement cct 1, 5009AL2( $f_0/2$ ),no load INHN=open, $f_0=24MHz$ $f_{OUT}=12MHz$	$V_{DD}=2.5V$	-	0.6	1.2
			$V_{DD}=3.3V$	-	0.8	1.6
			$V_{DD}=5.0V$		1.0	2.0
		Measurement cct 1, 5009AL3( $f_0/4$ ),no load INHN=open, $f_0=24MHz$ $f_{OUT}=6MHz$	$V_{DD}=2.5V$	-	0.6	1.3
			$V_{DD}=3.3V$	-	0.7	1.5
			$V_{DD}=5.0V$		0.8	1.6
		Measurement cct 1, 5009AL4( $f_0/8$ ),no load INHN=open, $f_0=24MHz$ $f_{OUT}=3MHz$	$V_{DD}=2.5V$	-	0.4	0.8
			$V_{DD}=3.3V$	-	0.5	1.0
			$V_{DD}=5.0V$		0.6	1.2
		Measurement cct 1, 5009AL5( $f_0/16$ ),no load INHN=open, $f_0=24MHz$ $f_{OUT}=1.5MHz$	$V_{DD}=2.5V$	-	0.4	0.8
			$V_{DD}=3.3V$	-	0.4	0.8
			$V_{DD}=5.0V$		0.5	1.0
		Measurement cct 1, 5009AL6( $f_0/32$ ),no load INHN=open, $f_0=24MHz$ $f_{OUT}=0.75MHz$	$V_{DD}=2.5V$	-	0.4	0.8
			$V_{DD}=3.3V$	-	0.4	0.8
			$V_{DD}=5.0V$		0.5	1.0
		Measurement cct 1, 5009AL6( $f_0/32$ ),no load INHN=open, $f_0=24MHz$ $f_{OUT}=0.375MHz$	$V_{DD}=2.5V$	-	0.4	0.8
			$V_{DD}=3.3V$	-	0.4	0.8
			$V_{DD}=5.0V$		0.5	1.0
$I_{ST}$	Standby current	Measurement cct1, INHN=LOW	-	-	10	uA
$R_{UP1}$	INHN pull-up resistance	Measurement cct6	0.4	1.5	8	M $\Omega$
$R_{UP2}$			30	70	150	K $\Omega$
$R_f$	Oscillator feedback resistance	-	70	100	140	K $\Omega$
$C_G$	Oscillator capacitance	Design value(a monitor pattern on a wafer is tested),Excluding parasitic capacitance	4.8	6	7.2	pF
$C_D$			8	10	12	pF



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# XO5009ALx-K Series

## High Performance

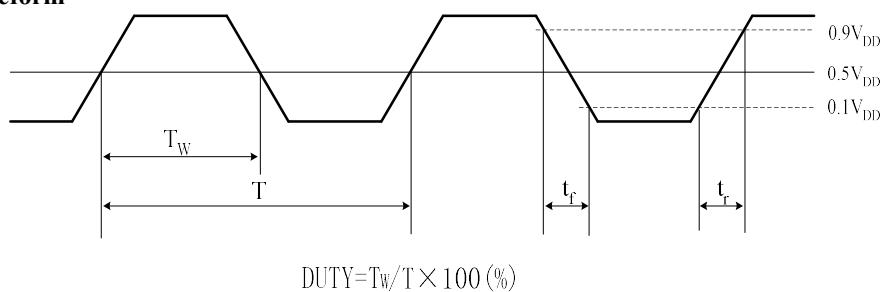
### Fundamental Crystal Oscillator IC

## AC Electrical Characteristics

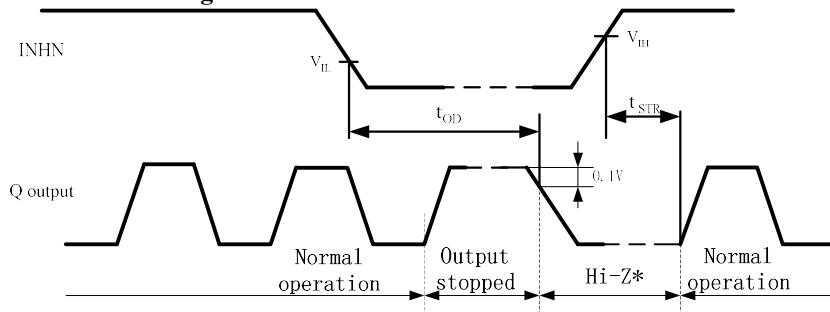
XO5009AL Series( $V_{DD}$ =2.2 to 5.5,  $T_a$ =-45 to 85°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Type	Max	Unit
Output rise time	$t_{r1}$	Measurement cct1,CL=15pf, $0.1V_{DD}$ to $0.9V_{DD}$	-	3.0	5.0	ns
	$t_{r2}$	$V_{DD}=4.5$ to $5.5$ V	-	2.0	3.0	ns
Output fall time	$t_{f1}$	Measurement cct1,CL=15pf, $0.1V_{DD}$ to $0.9V_{DD}$	-	3.0	5.0	ns
	$t_{f2}$	$V_{DD}=4.5$ to $5.5$ V	-	2.0	3.0	ns
Output rise time	$t_{r1}$	Measurement cct1,CL=50pf, $0.1V_{DD}$ to $0.9V_{DD}$	-	5.0	10	ns
	$t_{r2}$	$V_{DD}=4.5$ to $5.5$ V	-	4.0	8	ns
Output fall time	$t_{f1}$	Measurement cct1,CL=50pf, $0.1V_{DD}$ to $0.9V_{DD}$	-	5.0	10	ns
	$t_{f2}$	$V_{DD}=4.5$ to $5.5$ V	-	4.0	8	ns
Output duty cycle	Duty	Measurement cct 1, $T_a=25^\circ\text{C}$ , $C_L=15\text{pF}$	45	50	55	%
Output disable delay time	$t_{OD}$	Measurement cct 1, $T_a=25^\circ\text{C}$ , $C_L \leq 15\text{pF}$	-	-	50	us

### Output switching waveform



### Output disable and oscillation start timing chart



When INHN goes HIGH to LOW, the Q output goes HIGH once and then becomes high impedance.

When INHN goes LOW to HIGH, the Q output from high impedance to normal output operation when the oscillation starts (oscillation is detected)

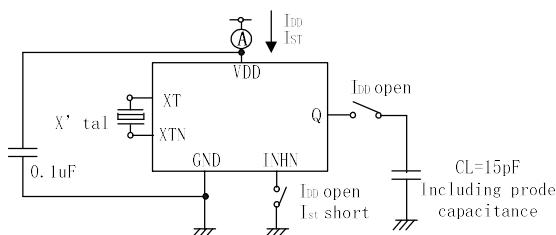
\*: the high -impedance interval in the figure is shown as a LOW level due to the  $1\text{K}\Omega$  pull-down resistor connected to the Q pin(see “Measurement circuit 2” in the “Measurement circuits” section)



## Measurement Circuit

### Measurement cct1

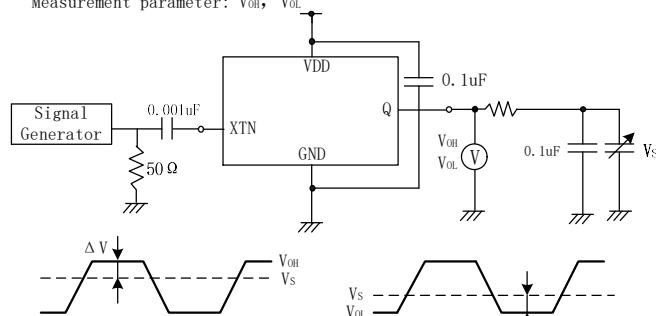
Measurement parameter:  $I_{DD}$ ,  $I_{ST}$ , Duty,  $t_r$ ,  $t_f$



Note: The AC characteristics are observed using an oscilloscope on pin Q.

### Measurement cct3

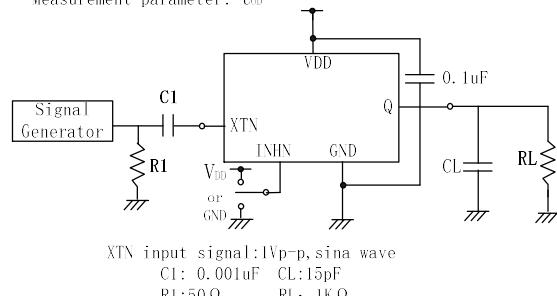
Measurement parameter:  $V_{OH}$ ,  $V_{OL}$



XTN input signal: 1Vp-p, sına wave

### Measurement cct2

Measurement parameter:  $t_{op}$

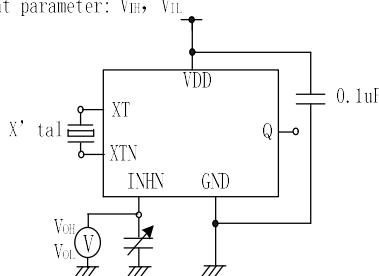


XTN input signal: 1Vp-p, sına wave

C1: 0.001uF CL: 15pF  
R1: 50Ω RL: 1KΩ

### Measurement cct4

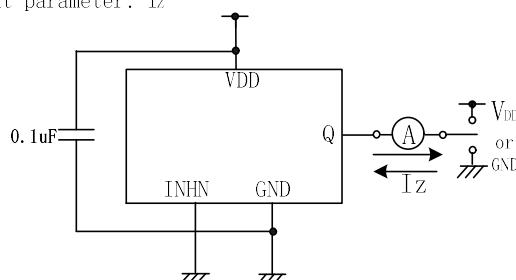
Measurement parameter:  $V_{IH}$ ,  $V_{IL}$



$V_{IH}$ : Voltage is 0V to  $V_{DD}$  transition that changes the output state.  
 $V_{IL}$ : Voltage is  $V_{DD}$  to 0V transition that changes the output state.  
INHN has an oscillation stop function

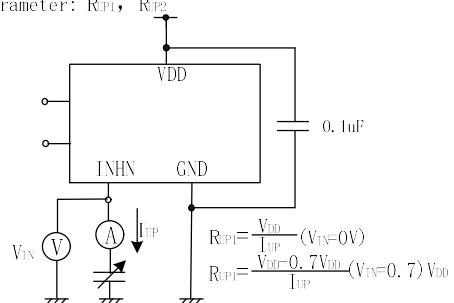
### Measurement cct5

Measurement parameter:  $I_Z$



### Measurement cct6

Measurement parameter:  $R_{P1}$ ,  $R_{P2}$





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High Performance  
Fundamental Crystal Oscillator IC**

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Revision	Description	DATE
V1.0	Initial release	2022/12/14
V1.1	Correct some type wrong.	2025/4/15